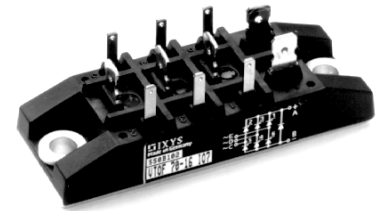
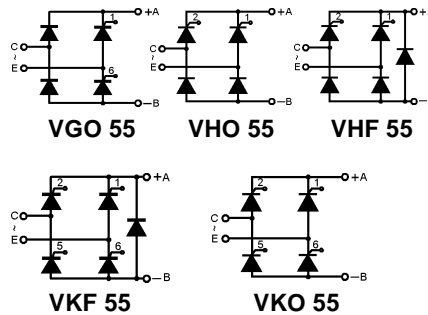


# Single Phase Rectifier Bridge

$I_{dAV} = 53 \text{ A}$   
 $V_{RRM} = 800-1600 \text{ V}$

Preliminary data

| $V_{RSM}$<br>$V_{DSM}$<br>V | $V_{RRM}$<br>$V_{DRM}$<br>V | Type         |
|-----------------------------|-----------------------------|--------------|
| 800                         | 800                         | xxx 55-08io7 |
| 1200                        | 1200                        | xxx 55-12io7 |
| 1400                        | 1400                        | xxx 55-14io7 |
| 1600                        | 1600                        | xxx 55-16io7 |
| xxx = type                  |                             |              |



| Symbol                  | Test Conditions  | Maximum Ratings   |
|-------------------------|--|---|
| $I_{dAV}$ ①             | $T_K = 85^\circ\text{C}$ , module  | 53 A  |
| $I_{dAVM}$ ①            | module   | 53 A  |
| $I_{FRMS}$ , $I_{TRMS}$ | per leg  | 41 A  |
| $I_{FSM}$ , $I_{TSM}$   | $T_{VJ} = 45^\circ\text{C}$ ;<br>$V_R = 0 \text{ V}$   | $t = 10 \text{ ms}$ (50 Hz), sine 550 A<br>$t = 8.3 \text{ ms}$ (60 Hz), sine 600 A                                 |
|                         | $T_{VJ} = T_{VJM}$<br>$V_R = 0 \text{ V}$  | $t = 10 \text{ ms}$ (50 Hz), sine 500 A<br>$t = 8.3 \text{ ms}$ (60 Hz), sine 550 A                                 |
| $I^2t$                  | $T_{VJ} = 45^\circ\text{C}$<br>$V_R = 0 \text{ V}$   | $t = 10 \text{ ms}$ (50 Hz), sine 1520 A <sup>2</sup> s<br>$t = 8.3 \text{ ms}$ (60 Hz), sine 1520 A <sup>2</sup> s |
|                         | $T_{VJ} = T_{VJM}$<br>$V_R = 0 \text{ V}$  | $t = 10 \text{ ms}$ (50 Hz), sine 1250 A <sup>2</sup> s<br>$t = 8.3 \text{ ms}$ (60 Hz), sine 1250 A <sup>2</sup> s |
| $(di/dt)_{cr}$          | $T_{VJ} = 125^\circ\text{C}$<br>$f = 50 \text{ Hz}$ , $t_p = 200 \mu\text{s}$<br>$V_D = 2/3 V_{DRM}$<br>$I_G = 0.3 \text{ A}$ ,<br>$di_G/dt = 0.3 \text{ A}/\mu\text{s}$ | repetitive, $I_T = 50 \text{ A}$ 150 A/ $\mu\text{s}$   |
|                         |  | non repetitive, $I_T = 1/2 \cdot I_{dAV}$ 500 A/ $\mu\text{s}$  |
| $(dv/dt)_{cr}$          | $T_{VJ} = T_{VJM}$ ; $V_{DR} = 2/3 V_{DRM}$<br>$R_{GK} = \infty$ ; method 1 (linear voltage rise)  | 1000 V/ $\mu\text{s}$   |
| $V_{RGM}$               |  | 10 V  |
| $P_{GM}$                | $T_{VJ} = T_{VJM}$<br>$I_T = I_{TAVM}$   | $t_p = 30 \mu\text{s}$ $\leq 10 \text{ W}$  |
|                         |  | $t_p = 500 \mu\text{s}$ $\leq 5 \text{ W}$  |
|                         |  | $t_p = 10 \text{ ms}$ $\leq 1 \text{ W}$  |
| $P_{GAVM}$              |  | 0.5 W   |
| $T_{VJ}$                |  | -40...+125 °C   |
| $T_{VJM}$               |  | 125 °C  |
| $T_{stg}$               |  | -40...+125 °C   |
| $V_{ISOL}$              | 50/60 Hz, RMS  | $t = 1 \text{ min}$ 2500 V~   |
|                         | $I_{ISOL} \leq 1 \text{ mA}$   | $t = 1 \text{ s}$ 3000 V~   |
| $M_d$                   | Mounting torque (M5)<br>(10-32 UNF)  | 5 ± 15 % Nm   |
|                         |  | 44 ± 15 % lb.in.  |
| Weight                  |  | 110 g   |

## Features

- Package with copper base plate
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- 1/4" fast-on power terminals

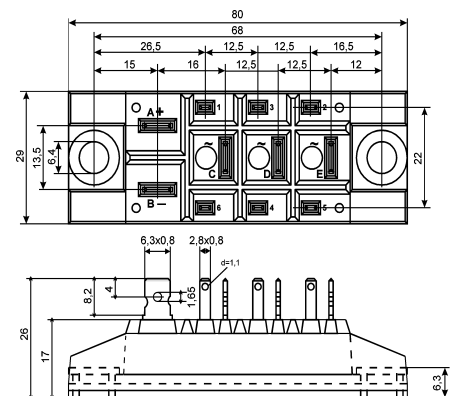
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight

## Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747 refer to a single diode/thyristor unless otherwise stated  
① for resistive load at bridge output. IXYS reserves the right to change limits, test conditions and dimensions.

| Symbol     | Test Conditions  | Characteristic Values |                     |
|------------|--|-----------------------|---------------------|
| $I_D, I_R$ | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$   | $\leq$                | 5 mA                |
| $V_T$      | $I_T = 80 \text{ A}; T_{VJ} = 25^\circ\text{C}$  | $\leq$                | 1.64 V              |
| $V_{T0}$   | For power-loss calculations only   |                       | 0.85 V              |
| $r_T$      |  |                       | 11 m $\Omega$       |
| $V_{GT}$   | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$   | $\leq$                | 1.5 V               |
|            | $T_{VJ} = -40^\circ\text{C}$   | $\leq$                | 1.6 V               |
| $I_{GT}$   | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$   | $\leq$                | 100 mA              |
|            | $T_{VJ} = -40^\circ\text{C}$   | $\leq$                | 200 mA              |
| $V_{GD}$   | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$  | $\leq$                | 0.2 V               |
| $I_{GD}$   |  | $\leq$                | 5 mA                |
| $I_L$      | $T_{VJ} = 25^\circ\text{C}; t_p = 10 \mu\text{s}$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$  | $\leq$                | 450 mA              |
| $I_H$      | $T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$  | $\leq$                | 200 mA              |
| $t_{gd}$   | $T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$   | $\leq$                | 2 $\mu\text{s}$     |
| $t_q$      | $T_{VJ} = T_{VJM}; I_T = 20 \text{ A}, t_p = 200 \mu\text{s}; di/dt = -10 \text{ A}/\mu\text{s}$<br>$V_R = 100 \text{ V}; dv/dt = 15 \text{ V}/\mu\text{s}; V_D = 2/3 V_{DRM}$ | typ.                  | 250 $\mu\text{s}$   |
| $R_{thJC}$ | per thyristor / Diode; DC  |                       | 0.9 K/W             |
|            | per module   |                       | 0.18 K/W            |
| $R_{thJK}$ | per thyristor / Diode; DC  |                       | 1.1 K/W             |
|            | per module   |                       | 0.22 K/W            |
| $d_s$      | Creeping distance on surface   |                       | 16.1 mm             |
| $d_A$      | Creepage distance in air   |                       | 7.1 mm              |
| $a$        | Max. allowable acceleration  |                       | 50 m/s <sup>2</sup> |